QUICKSWITCH® PRODUCTS
2.5V / 3.3V 20-BIT 2-PORT, HIGH BANDWIDTH BUS SWITCH

IDTQS3VH16210

FEATURES:

- N channel FET switches with no parasitic diode to Vcc
  - Isolation under power-off conditions
  - No DC path to Vcc or GND
  - 5V tolerant in OFF and ON state
- 5V tolerant I/Os
- Low R_{ON} - 4Ω typical
- Flat R_{ON} characteristics over operating range
- Rail-to-rail switching 0 - 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- Excellent R_{ON} matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth - up to 500 MHz
- LVTTL-compatible control Inputs
- Undershoot Clamp Diodes on all switch and control Inputs
- Low I/O capacitance, 4pF typical
- Available in SSOP and TSSOP packages

APPLICATIONS:

- Hot-swapping
- 10/100 Base-T, Ethernet LAN switch
- Low distortion analog switch
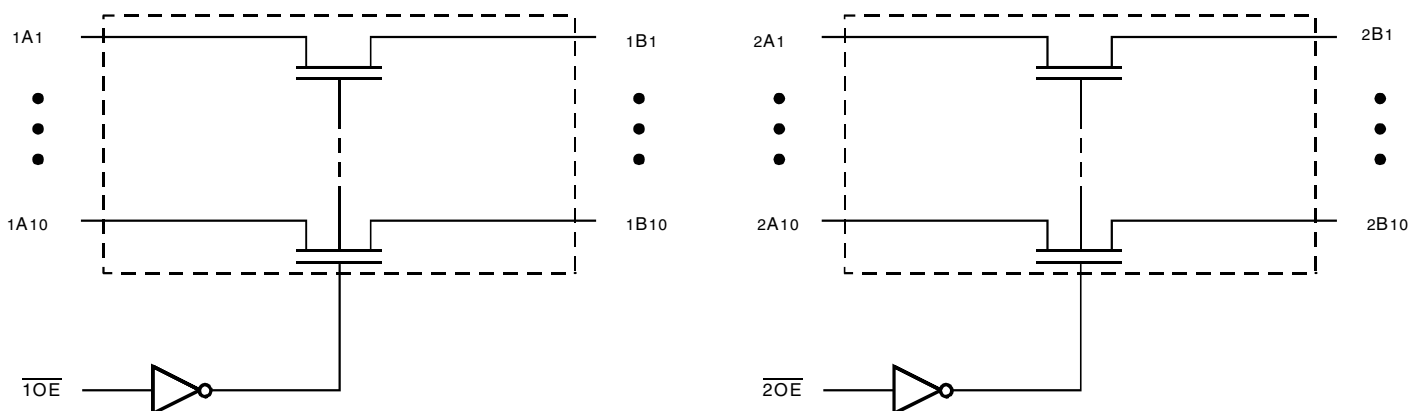- Replaces mechanical relay
- ATM 25/155 switching

DESCRIPTION:

The QS3VH16210 HotSwitch with 20-bit flow-though pin is a high bandwidth bus switch. The QS3VH16210 has very low ON resistance, resulting in under 250ps propagation delay through the switch. The switches are controlled by active low enable ($\overline{xOE}$) controls. The QS3VH16210 is organized as a dual 10-bit, 2-port bus switch with separate, $\overline{xOE}$ control inputs. In the OFF and ON states, the switches are 5V-tolerant. In the OFF state, the switches offer very high impedance at the terminals.

The combination of near-zero propagation delay, high OFF impedance, and over-voltage tolerance makes the QS3VH16210 ideal for high performance communications applications.

The QS3VH16210 is characterized for operation from -40°C to +85°C.
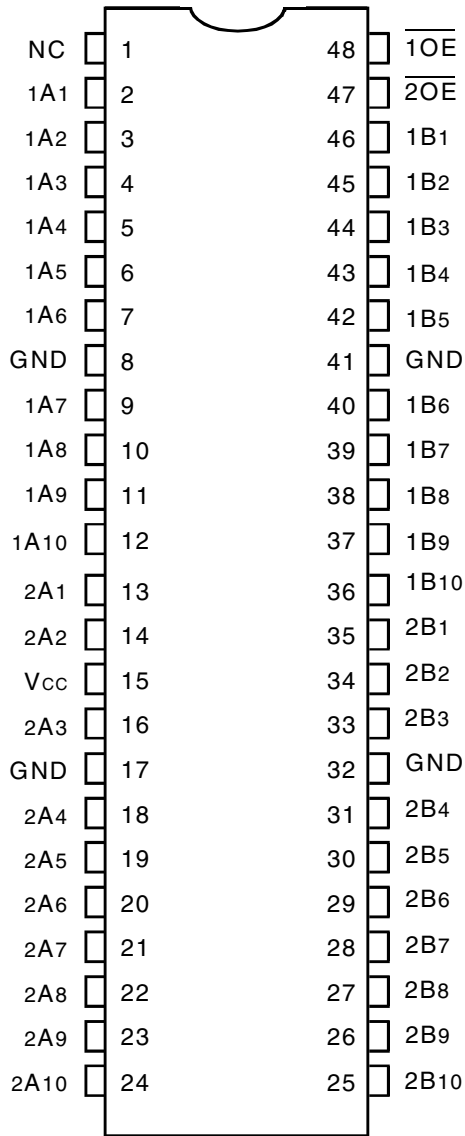
FUNCTIONAL BLOCK DIAGRAM

INDUSTRIAL TEMPERATURE RANGE

MARCH 2002

DSC-5881/4

PIN CONFIGURATION

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            _____
    NC  [ 1              48 ]  1OE
   1A1  [ 2              47 ]  2OE
   1A2  [ 3              46 ]  1B1
   1A3  [ 4              45 ]  1B2
   1A4  [ 5              44 ]  1B3
   1A5  [ 6              43 ]  1B4
   1A6  [ 7              42 ]  1B5
   GND  [ 8              41 ]  GND
   1A7  [ 9              40 ]  1B6
   1A8  [ 10             39 ]  1B7
   1A9  [ 11             38 ]  1B8
  1A10  [ 12             37 ]  1B9
   2A1  [ 13             36 ]  1B10
   2A2  [ 14             35 ]  2B1
   VCC  [ 15             34 ]  2B2
   2A3  [ 16             33 ]  2B3
   GND  [ 17             32 ]  GND
   2A4  [ 18             31 ]  2B4
   2A5  [ 19             30 ]  2B5
   2A6  [ 20             29 ]  2B6
   2A7  [ 21             28 ]  2B7
   2A8  [ 22             27 ]  2B8
   2A9  [ 23             26 ]  2B9
  2A10  [ 24             25 ]  2B10
            _____
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SSOP/ TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Description	Max.	Unit
V_{TERM}[2]	Supply Voltage to Ground	− 0.5 to 4.6	V
V_{TERM}[3]	DC Switch Voltage V_S	− 0.5 to 5.5	V
V_{TERM}[3]	DC Input Voltage V_{IN}	− 0.5 to 5.5	V
V_{AC}	AC Input Voltage (pulse width ≤20ns)	− 3	V
I_{OUT}	DC Output Current (max. current/pin)	120	mA
T_{STG}	Storage Temperature	-65 to +150	$^\circ$C

NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. V_{CC} terminals.
3. All terminals except V_{CC}.

CAPACITANCE (T_A = +25°C, f = 1MHz, V_{IN} = 0V, V_{OUT} = 0V)

Symbol	Parameter[1]	Typ.	Max.	Unit
C_{IN}	Control Inputs	3	5	pF
$C_{I/O}$	Quickswitch Channels (Switch OFF)	4	6	pF
$C_{I/O}$	Quickswitch Channels (Switch ON)	8	12	pF

NOTE:
1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	Description
$x\overline{OE}$	Bus Enables (Active LOW)
1A1 - 1A10, 2A1 - 2A10	Bus A
1B1 - 1B10, 2B1 - 2B10	Bus B

FUNCTION TABLE (EACH 10-BIT BUS SWITCH) [1]

Control Input $x\overline{OE}$	Function
L	A port = B port
H	Disconnect

NOTE:
1. H = HIGH Voltage Level
   L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Industrial: T_A = –40°C to +85°C, V_{CC} = 3.3V ± 0.3V

Symbol	Parameter	Test Conditions			Min.	Typ.[1]	Max.	Unit
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs	V_{CC} = 2.3V to 2.7V		1.7	—	—	V
			V_{CC} = 2.7V to 3.6V		2	—	—	
V_{IL}	Input LOW Voltage	Guaranteed Logic HIGH for Control Inputs	V_{CC} = 2.3V to 2.7V		—	—	0.7	V
			V_{CC} = 2.7V to 3.6V		—	—	0.8	
I_{IN}	Input Leakage Current (Control Inputs)	$0V \leq V_{IN} \leq V_{CC}$			—	—	±1	µA
I_{OZ}	Off-State Current (Hi-Z)	$0V \leq V_{OUT} \leq 5V$, Switches OFF			—	—	±1	µA
I_{OFF}	Data Input/Output Power Off Leakage	V_{IN} or V_{OUT} 0V to 5V, V_{CC} = 0V			—	—	±1	µA
R_{ON}	Switch ON Resistance	V_{CC} = 2.3V (Typ. at V_{CC} = 2.5V)	V_{IN} = 0V	I_{ON} = 30mA	—	6	8	Ω
			V_{IN} = 1.7V	I_{ON} = 15mA	—	7	9	
		V_{CC} = 3V	V_{IN} = 0V	I_{ON} = 30mA	—	4	6	
			V_{IN} = 2.4V	I_{ON} = 15mA	—	5	8	

NOTE:

1. Typical values are at V_{CC} = 3.3V and T_A = 25°C, unless otherwise noted.

TYPICAL ON RESISTANCE vs V_{IN} AT V_{CC} = 3.3V
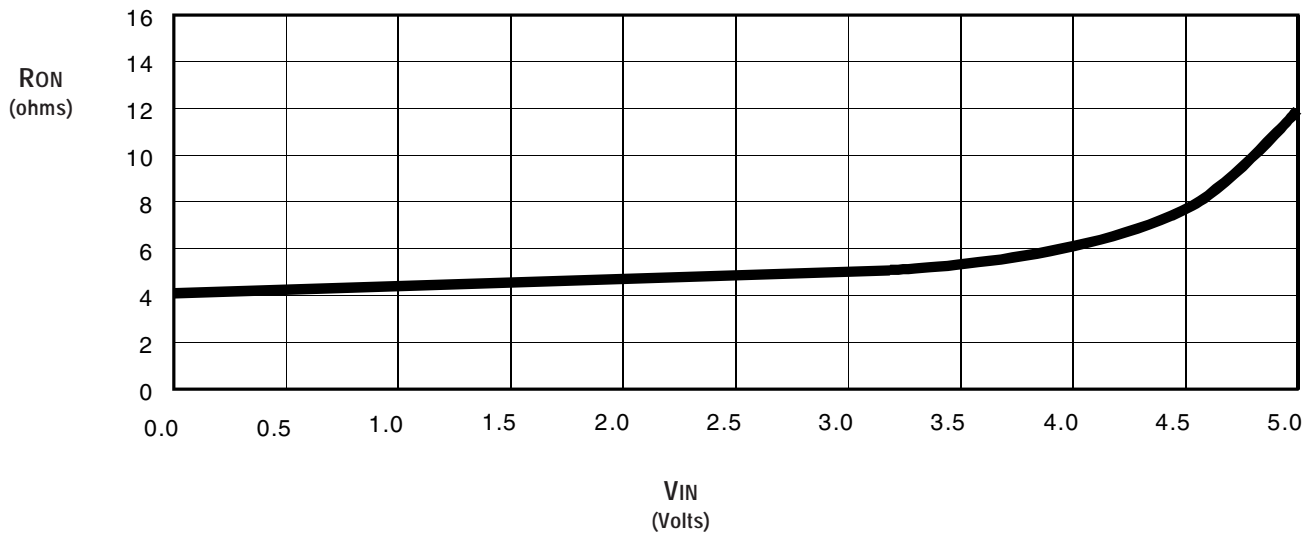
POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions[1]	Min.	Typ.	Max.	Unit
I_{CCQ}	Quiescent Power Supply Current	V_{CC} = Max., V_{IN} = GND or V_{CC}, f = 0	—	1.5	3	mA
ΔI_{CC}	Power Supply Current[2,3] per Input HIGH	V_{CC} = Max., V_{IN} = 3V, f = 0 per Control Input	—	—	30	µA
I_{CCD}	Dynamic Power Supply Current[4]	V_{CC} = 3.3V, A and B Pins Open, Control Inputs Toggling @ 50% Duty Cycle	See Typical I_{CCD} vs Enable Frequency graph below			

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
2. Per input driven at the specified level. A and B pins do not contribute to ΔI_{CC}.
3. This parameter is guaranteed but not tested.
4. This parameter represents the current required to switch internal capacitance at the specified frequency. The A and B inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

TYPICAL I_{CCD} vs ENABLE FREQUENCY CURVE AT V_{CC} = 3.3V

ENABLE FREQUENCY (MHZ)
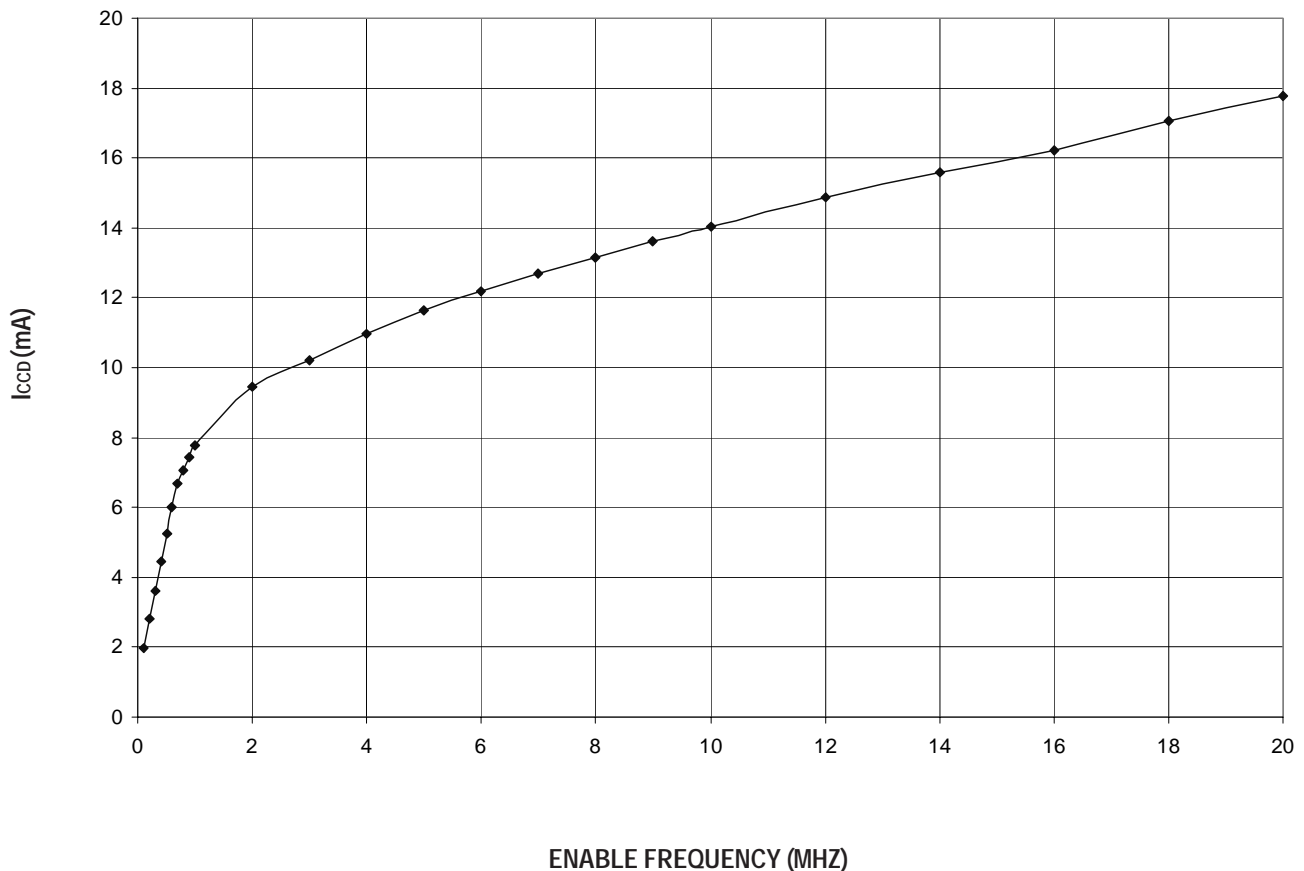
SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T_A = -40°C to +85°C

Symbol	Parameter	V_{CC} = 2.5 ± 0.2V [1]		V_{CC} = 3.3 ± 0.3V [1]		Unit
		Min. [4]	Max.	Min. [4]	Max.	
t_{PLH}	Data Propagation Delay[2,3]	—	0.2	—	0.2	ns
t_{PHL}	A to B or B to A					
t_{PZH}	Switch Turn-On Delay	1.5	9	1.5	9	ns
t_{PZL}	$\overline{xBE}$ to xA or xB					
t_{PHZ}	Switch Turn-Off Delay	1.5	8.5	1.5	8.5	ns
t_{PLZ}	$\overline{xBE}$ to xA or xB					
$f_{\overline{xOE}}$	Operating Frequency - Enable[2,5]	—	7.5	—	20	MHz

NOTES:

1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.
2. This parameter is guaranteed but not production tested.
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.2ns at C_L = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.
4. Minimums are guaranteed but not production tested.
5. Maximum toggle frequency for $\overline{xOE}$ control input (pass voltage > V_{CC}, V_{IN} = 5V, R_{LOAD} > 1MΩ, no C_{LOAD}).
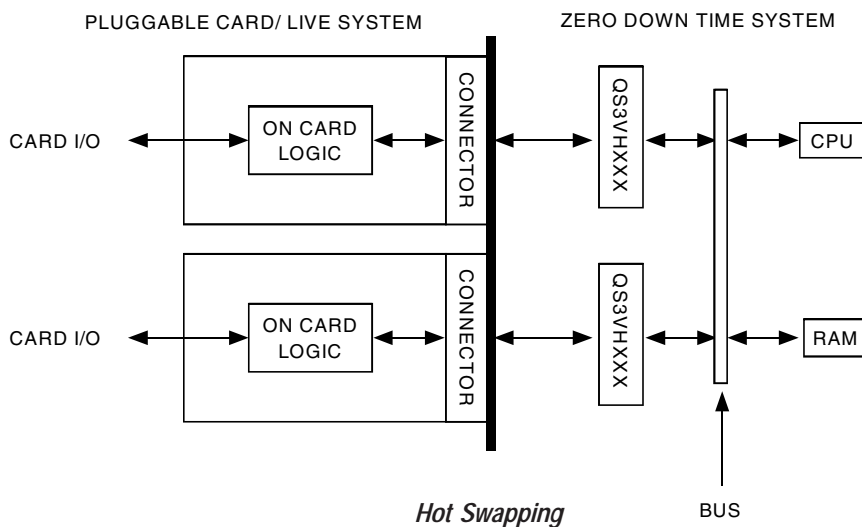
SOME APPLICATIONS FOR HOTSWITCH PRODUCTS
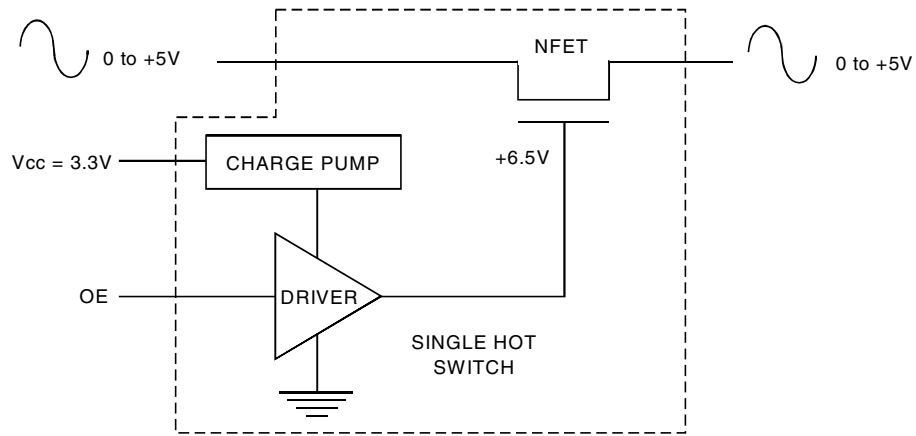
Rail-to-Rail Switching
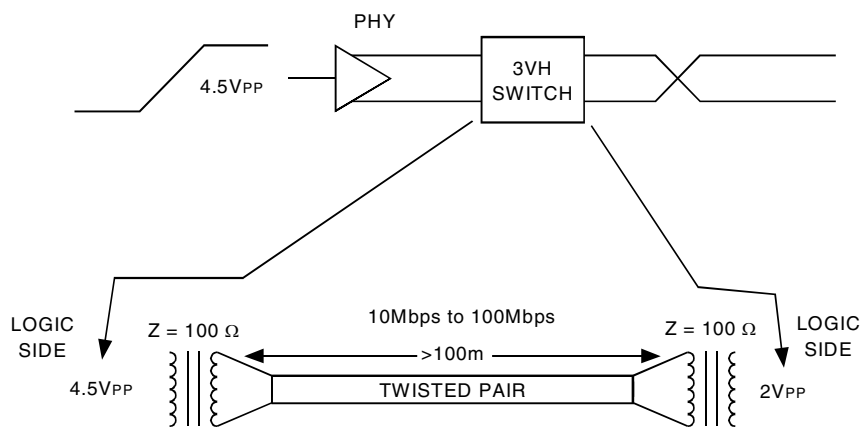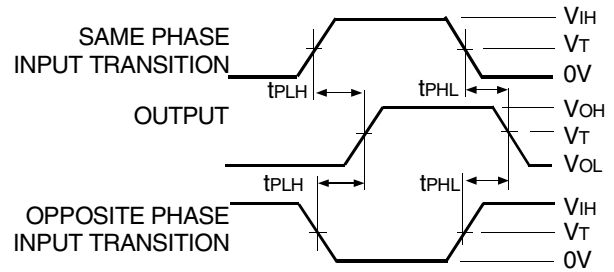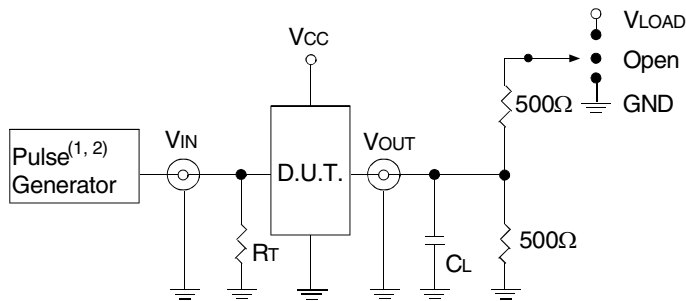
Fast Ethernet Data Switching (LAN Switch)
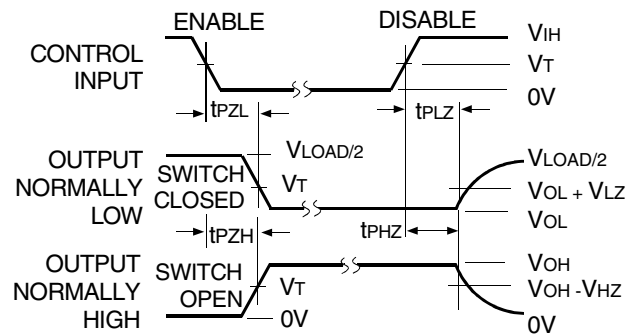
Hot Swapping

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)}$ = 3.3V ± 0.3V	$V_{CC}^{(2)}$ = 2.5V ± 0.2V	Unit
V_{LOAD}	6	2 x V_{CC}	V
V_{IH}	3	V_{CC}	V
V_T	1.5	$V_{CC}/2$	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF

Propagation Delay

Test Circuits for All Outputs

NOTE:
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

DEFINITIONS:
C_L = Load capacitance: includes jig and probe capacitance.
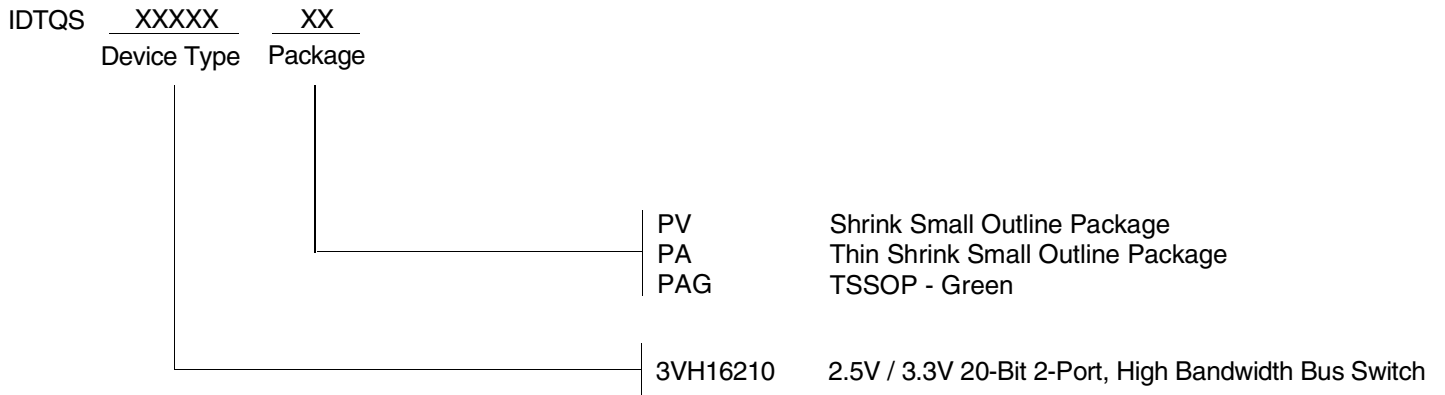R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:
1. Pulse Generator for All Pulses: Rate ≤ 1.0MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 1.0MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open

ORDERING INFORMATION

IDTQS   <u>XXXXX</u>   <u>XX</u>

Device Type   Package

PV	Shrink Small Outline Package
PA	Thin Shrink Small Outline Package
PAG	TSSOP - Green

3VH16210	2.5V / 3.3V 20-Bit 2-Port, High Bandwidth Bus Switch